



International Academy, Research, and Industry Association

Best Paper Award

Competitive Mechanisms of Resistive Switching in
Nanooxide Based Memory Cells

By

Dmitriy Stremous, Aleksandr Danilyuk, Denis Podryabinkin, Victor Borisenko

Presented during ICQNM 2015, The Ninth International Conference on Quantum, Nano/Bio, and Micro Technologies,
held in Venice, Italy - August 23 - 28, 2015


IARIA Board

